

THE AH3369Q IS NOT RECOMMENDED FOR NEW DESIGNS. PLEASE USE THE AH3329Q.

AH3369Q



HIGH-VOLTAGE LOW-SENSITIVITY

AUTOMOTIVE HALL-EFFECT UNIPOLAR SWITCH

Description

The AH3369Q is an AEC-Q100 gualified high-voltage low-sensitivity Hall-effect unipolar switch IC designed for position and proximity sensing in automotive applications, such as in seat and seatbelt buckle, steering lock/immobilization, gear stick, transmission actuator and gear position, HVAC compression, wiper, door/trunk closure, etc. To support a wide range of the demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper-stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3369Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a Zener clamp on the supply. The output has an overcurrent limit and a Zener clamp.

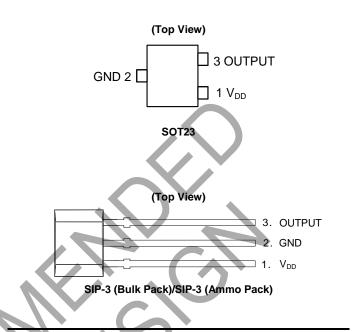
The single open-drain output can be switched on with south pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (BOP), the output is switched on (pulled low) and is held on until magnetic flux density B is lower than the release point (BRP). The output remains switched off for north pole fields to or no magnetic fields.

Features

- Unipolar Operation
- Low Sensitivity: BOP and BRP of 175G and 150G Typical
- Single Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- **Chopper-Stabilized Design Provides**
 - Superior Temperature Stability .
 - Minimal Switch Point Drift
 - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Reverse Blocking Diode
- Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM > 8kV, CDM: > 2kV
- AEC-Q100 Grade 0 Qualified
- Industry Standard SOT23, SIP-3 (Ammo Pack) and SIP-3 (Bulk Pack) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The AH3369Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Pin Assignments



Applications

- Position and proximity sensing in automotive applications
- Open and close detection
- Position detection
- Level detection
- Flow meters
- Contactless switches

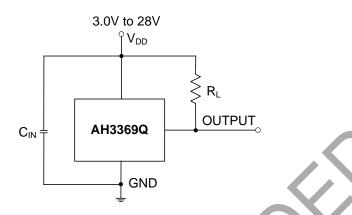
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Notes:



Typical Applications Circuit (Note 4)



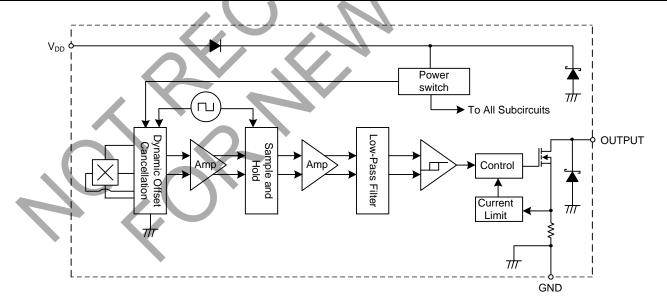
Note: 4. C_{IN} is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF to 100nF. R_L is the pullup resistor.

Pin Descriptions

Packages: SOT23, SIP-3 (Ammo Pack) and SIP-3 (Bulk Pack)

Pin Number	Pin Name	Function
1	Vdd	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

Functional Block Diagram





Symbol	Characteris	Value	Unit				
Vdd	Supply Voltage (Note 6)	32	V				
Vddr	Reverse Supply Voltage (Note 6)		-32	V			
Vout_max	Output Off Voltage (Note 6)		32	V			
Іоит	Continuous Output Current	Continuous Output Current					
IOUT_R	Reverse Output Current	-50	mA				
В	Magnetic Flux Density	Unlimited					
PD	Package Power Dissipation	SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)	550	mW			
2	5	SOT23	230				
Ts	Storage Temperature Range	-65 to +165	°C				
TJ	Maximum Junction Temperature	+150	°C				
ESD HBM	Electrostatic Discharge Withstand—Human Bo	8	kV				
ESD MM	Electrostatic Discharge Withstand-Machine Machine	Model (MM)	800	V			
ESD CDM	Electrostatic Discharge Withstand—Charged I	Electrostatic Discharge Withstand—Charged Device Model (CDM)					

Absolute Maximum Ratings (Notes 5 & 6) (@TA = +25°C, unless otherwise specified.)

Notes: 5. Stresses greater than those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to *Absolute Maximum Ratings* for extended periods can affect device reliability.

6. The absolute maximum V_{DD} of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

Recommended Operating Conditions (@TA = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter Condition		Rating	Unit
Vdd	Supply Voltage	Operating	3.0 to 28	V
TA	Operating Temperature Range	Operating	-40 to +150	°C

Electrical Characteristics (Notes 7 & 8) (@T_A = -40°C to +150°C, V_{DD} = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Condition	Min	Тур	Max	Unit
Vout_on	Output ON Voltage	$I_{OUT} = 20 \text{mA}, \text{B} > B_{OP}$	_	0.2	0.4	V
Ilkg	Output Leakage Current (When Output is Off)	VOUT = 28V, B < BRP, Output Off	—	< 0.1	10	μA
la a	Supply Current	Output Open, TA = +25°C	_	3	3.5	mA
IDD	Supply Current	Output Open, T _A = -40°C to +150°C	_		4	mA
		V _{DD} = -18V, T _A = +25°C	—	0.6	—	μA
1	Deverse Supply Surrent	VDD = -18V, T _A = -40°C to +150°C	—	0.6	1500	μA
ldd_r	Reverse Supply Current	V _{DD} = -28V, T _A = +25°C	—	1.6	_	μA
		V _{DD} = -28V, T _A = -40°C to +150°C	_	1.6	2500	μA
tp_on	Device Power-On Time (Startup Time)	V _{DD} ≥ 3V, B > B _{OP} (Note 7)	—	10	_	μs
fc	Chopping Frequency	—	—	800	_	kHz
tD	Response Time Delay (Time from Magnetic Threshold Reached to the Start of the Output Rise or Fall)	(Note 9)	_	3.75	_	μs
tR	Output Rising Time (External Pullup Resistor R _L and Load Capacitance Dependent)	$R_L = 1k\Omega$, $C_L = 20pF$	_	0.2	1	μs
tF	Output Falling Time (Internal Switch Resistance and Load Capacitance Dependent)	$R_L = 1k\Omega, C_L = 20pF$	—	0.1	1	μs
IOCL	Output Current Limit	B > BOP (Note 10)	30	_	55	mA
Vz	Zener Clamp Voltage	Ipp = 5mA	28			V

Notes: 7. When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the startup time of 10µs typical from the operating voltage reaching 3V.

8. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

9. Guaranteed by design, process control and characterization. Not tested in production.

10. The device will limit the output current IOUT to current limit of IOCL.

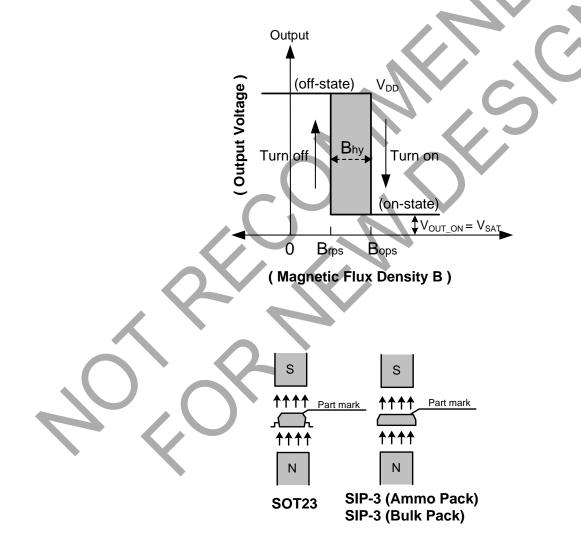


Magnetic Characteristics (Notes 11 & 12) (T_A = -40°C to +150°C, V_{DD} = 3.0V to 28V, unless otherwise specified.)

				(1m	T = 10 Ga	auss)
Symbol	Parameter	Condition	Min	Тур	Max	Unit
Bops		V _{DD} = 12V, T _A = +25°C	—	175	_	
(South Pole to the Part Marking Side of SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) Packages)	Operation Point	$T_{A} = -40^{\circ}C \text{ to } +150^{\circ}C$	150	175	200	
BRPS		$V_{DD} = 12V, T_A = +25^{\circ}C$	_	150	_	0
(South Pole to the Part Marking Side of SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) Packages)	Release Point	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	125	150	180	Gauss
	Livetoracia (Nista 12)	$V_{DD} = 12V, T_A = +25^{\circ}C$	-	25	—	
Bhy (Bopx - Brpx)	Hysteresis (Note 13)	$T_{A} = -40^{\circ}C \text{ to } +150^{\circ}C$	18	25	35	

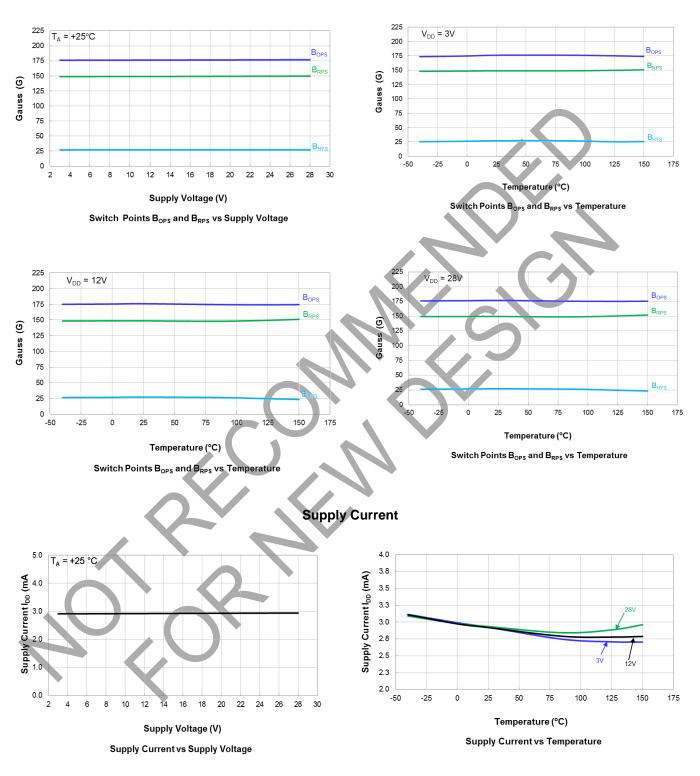
11. When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is Notes: valid after the startup time of 10µs typical from the operating voltage reaching 3V.

12. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization. 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.





Typical Operating Characteristics

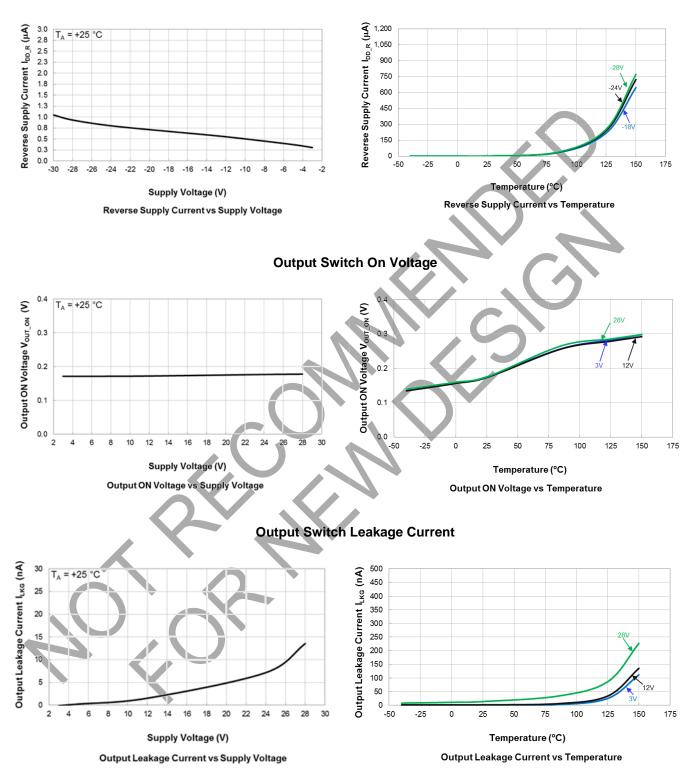


Output Switch Operate and Release Points (Magnetic Thresholds) – B_{OPS} and B_{RPS}



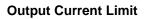
Typical Operating Characteristics (continued)

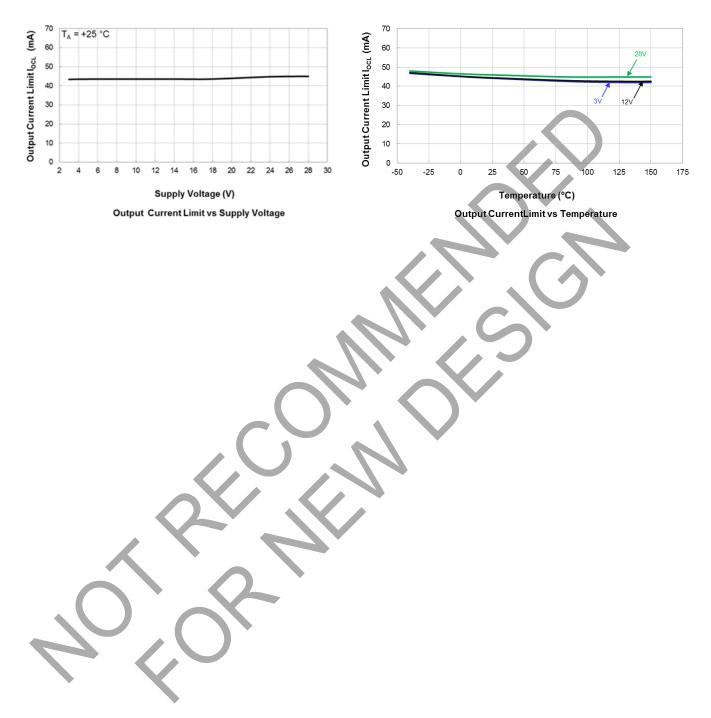
Supply Reverse Current





Typical Operating Characteristics (continued)



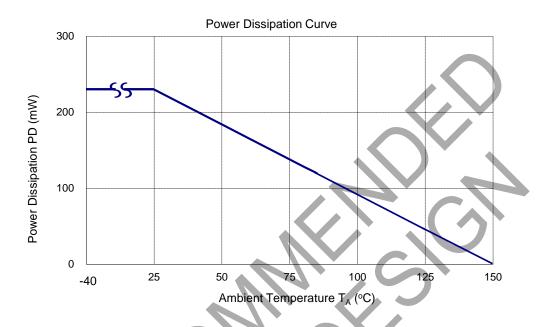




Thermal Performance Characteristics

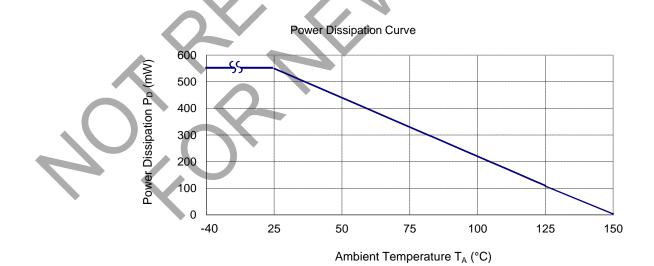
(1) Package Type: SOT23

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



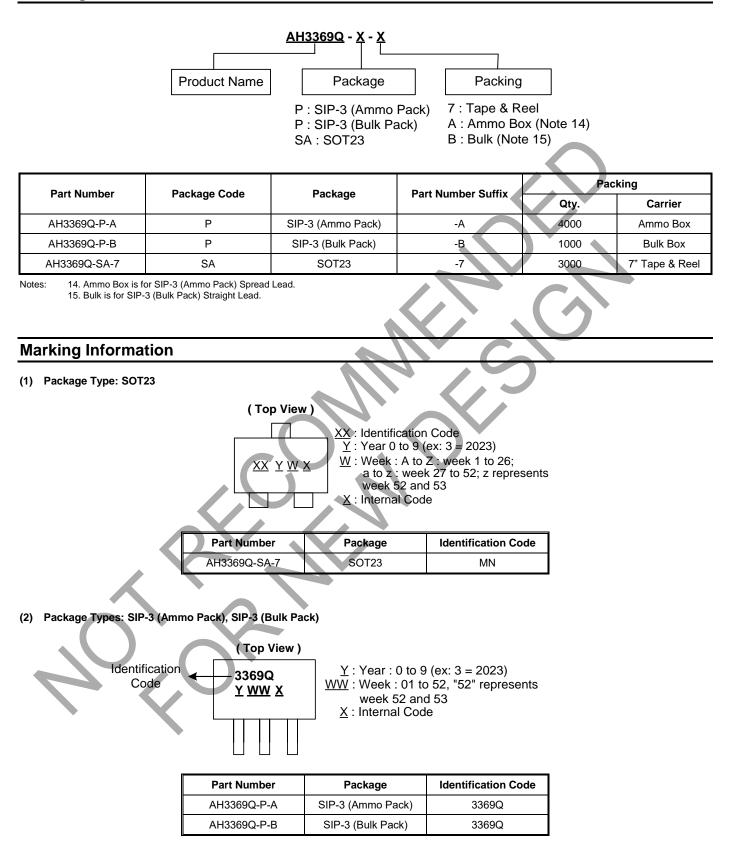
(2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

T₄ (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0





Ordering Information

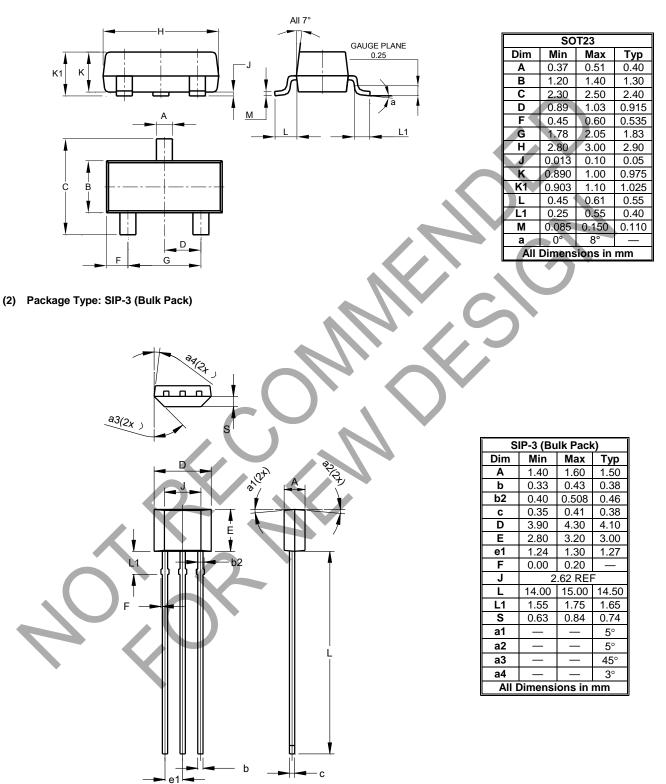




Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT23

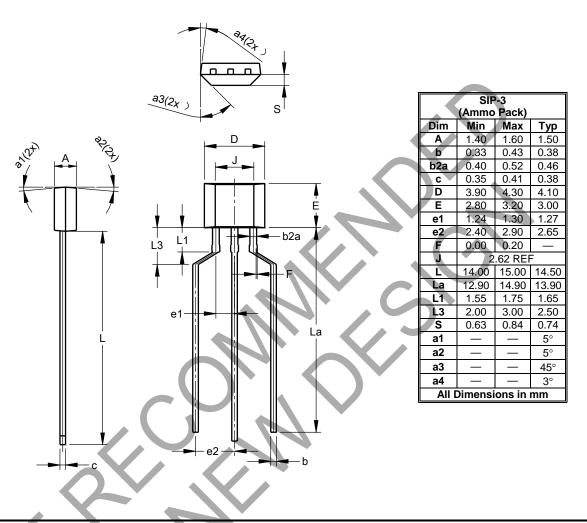




Package Outline Dimensions (continued) (All dimensions in mm.)

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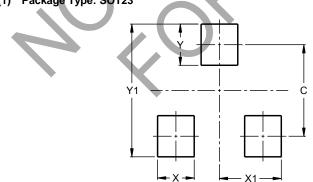
(3) Package Type: SIP-3 (Ammo Pack)



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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